# **Ultrafast Power Rectifier**

6 A, 600 V

# **RURD660S9A-F085**

The RURD660S9A–F085 is an ultrafast diode with soft recovery characteristics (trr < 83 ns). It has a low forward voltage drop and is of silicon nitride passivated ion–implanted epitaxial planar construction. This device is intended for use as a freewheeling/clamping diode and rectifier in a variety of switching power supplies and other power switching applications. Its low stored charge and ultrafast soft recovery minimize ringing and electrical noise in many power switching circuits, thus reducing powerloss in the switching transistors.

### Features

- High Speed Switching ( $t_{rr} = 63 \text{ ns}$  (Typ.) @  $I_F = 6 \text{ A}$ )
- Low Forward Voltage ( $V_F = 1.26 \text{ V}$  (Typ.) @  $I_F = 6 \text{ A}$ )
- Avalanche Energy Rated
- AEC-Q101 Qualified and PPAP Capable
- This is a Pb–Free Device

### Applications

- General Purpose
- Switching Mode Power Supply
- Power Switching Circuits

#### ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub> = 25°C unless otherwise noted) Symbol Parameter Ratings Unit Peak Repetitive Reverse Voltage 600 V V<sub>RRM</sub> V Working Peak Reverse Voltage 600 VRWM DC Blocking Voltage 600 V $V_{R}$ Average Rectified Forward Current 6 А IF(AV) @ $T_{C} = 25^{\circ}C$ Non-repetitive Peak Surge Current 60 А IFSM °C TJ, T<sub>STG</sub> Operating Junction and Storage - 55 to +175 Temperature

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### THERMAL CHARACTERISTICS (T<sub>C</sub> = 25°C unless otherwise noted)

Symbol	Parameter	Max	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	3	°C/W
R <sub>θJA</sub> (Note 1)	Maximum Thermal Resistance, Junction to Ambient	140	°C/W
R <sub>θJA</sub> (Note 2)	Maximum Thermal Resistance, Junction to Ambient	50	°C/W

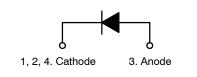
1. Mounted on a minimum pad follow by JEDEC standard.

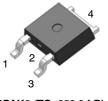
2. Mounted on a 1 in<sup>2</sup> pad of 2 oz copper follow by JEDEC standard.



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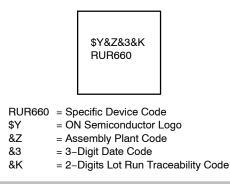
#### www.onsemi.com





DPAK3 (TO-252 3 LD) CASE 369AS

#### MARKING DIAGRAM



### **ORDERING INFORMATION**

See detailed ordering and shipping information on page 4 of this data sheet.

## RURD660S9A-F085

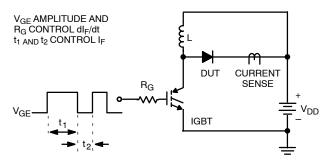
Symbol	Parameter	Condition		Min	Тур	Max	Unit
I <sub>R</sub>	Instantaneous Reverse Current	V <sub>R</sub> = 600 V	$T_C = 25^{\circ}C$		-	100	μΑ
	Guirent		$T_{C} = 175^{\circ}$	-	-	500	μΑ
V <sub>FM</sub> (Note 3)	Instantaneous Forward Voltage	I <sub>F</sub> = 6 A	$\begin{array}{l} T_C = 25^\circ C \\ T_C = 175^\circ \end{array}$	-	1.26 1.04	1.5 -	V V
t <sub>rr</sub> (Note 4)	Reverse Recovery Time	$I_F$ = 1 A, di/dt = 200 A/µs, V <sub>CC</sub> = 390 V	$T_C = 25^{\circ}C$	-	25	33	ns
		$I_F = 6 \text{ A}, \text{ di/dt} = 200 \text{ A/}\mu\text{s}, \text{ V}_{CC} = 390 \text{ V}$	$\begin{array}{l} T_{C}=25^{\circ}C\\ T_{C}=175^{\circ} \end{array}$	-	63 119	83 -	ns ns
t <sub>a</sub> t <sub>b</sub> Qrr	Reverse Recovery Time Reverse Recovery Charge	$I_F = 6 \text{ A}, \text{ di/dt} = 200 \text{ A/}\mu\text{s}, \text{ V}_{CC} = 390 \text{ V}$	$T_C = 25^{\circ}C$		23 40 151		ns ns nC
WAVL	, , ,	Avalanche Energy (L = 20 mH)		10	-	-	mJ

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

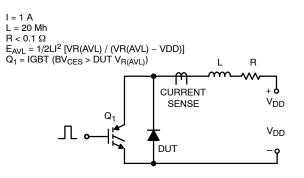
3. Pulse: Test Pulse width = 300 μs, Duty Cycle = 2%

4. Guaranteed by design

### **TEST CIRCUIT AND WAVEFORMS**









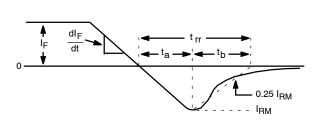
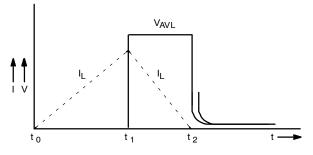


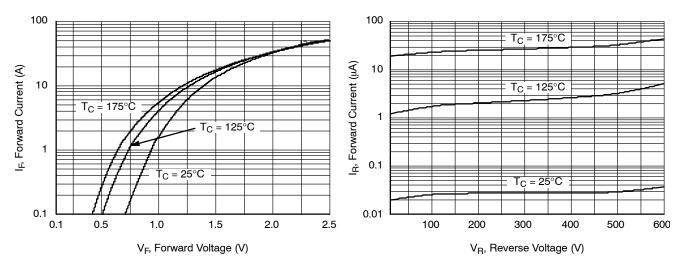
Figure 2. trr Waveforms and Definitions

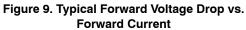


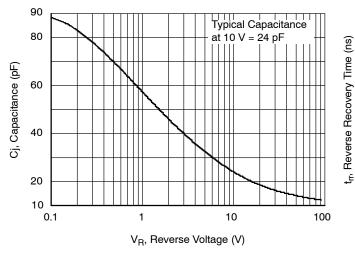


### RURD660S9A-F085

### **TYPICAL PERFORMANCE CHARACTERISTICS**

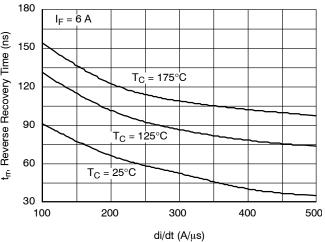




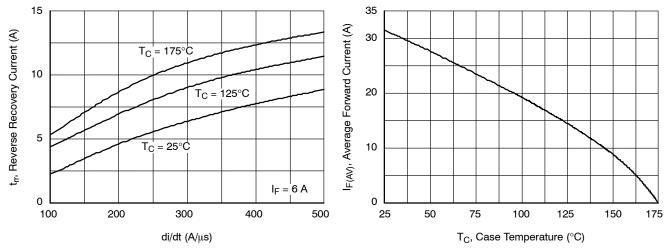
















### RURD660S9A-F085

### TYPICAL PERFORMANCE CHARACTERISTICS (continued)

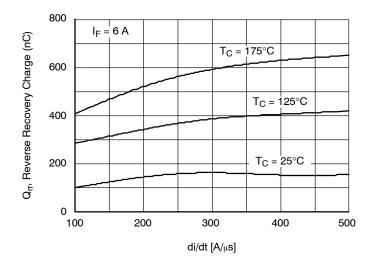
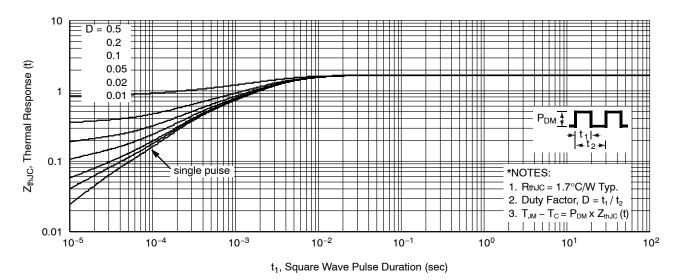
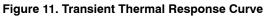


Figure 12. Reverse Recovery Charge



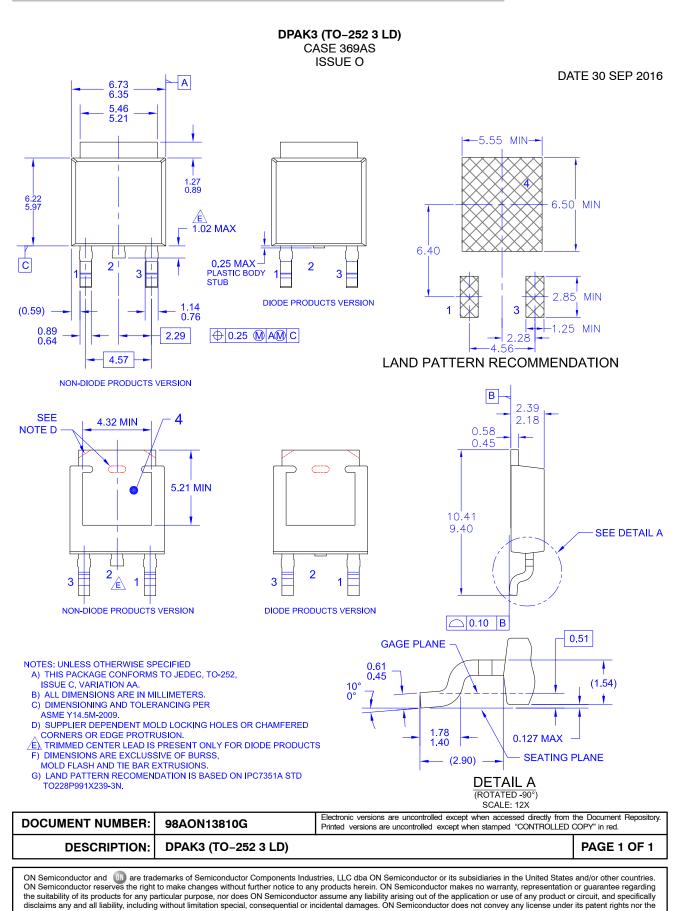


#### **ORDERING INFORMATION**

Device	Device Marking	Package	Shipping <sup>†</sup>
RURD660S9A-F085	RUR660	TO-252 3 LD (Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.





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